

# 74HC3G14-Q100; 74HCT3G14-Q100

Triple inverting Schmitt trigger

Rev. 3 — 1 February 2019

Product data sheet

## 1. General description

The 74HC3G14-Q100; 74HCT3G14-Q100 is a triple inverter with Schmitt-trigger inputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Complies with JEDEC standard no. 7A
- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
  - For 74HC3G14-Q100: CMOS level
  - For 74HCT3G14-Q100: TTL level
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times
- Multiple package options
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

## 3. Applications

- Wave and pulse shaper for highly noisy environments
- Astable multivibrators
- Monostable multivibrators

## 4. Ordering information

Table 1. Ordering information

| Type number      | Package           |        |   |          |
|------------------|-------------------|--------|---|----------|
|                  | Temperature range | Name   | Description   | Version  |
| 74HC3G14DP-Q100  | -40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | SOT505-2 |
| 74HCT3G14DP-Q100 |                   |        |   |          |
| 74HC3G14DC-Q100  | -40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm              | SOT765-1 |
| 74HCT3G14DC-Q100 |                   |        |   |          |

## 5. Marking

Table 2. Marking

| Type number      | Marking code [1] |
|------------------|------------------|
| 74HC3G14DP-Q100  | H14              |
| 74HCT3G14DP-Q100 | T14              |
| 74HC3G14DC-Q100  | H14              |
| 74HCT3G14DC-Q100 | T14              |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 6. Functional diagram



**Fig. 1. Logic symbol**



**Fig. 2. IEC logic symbol**

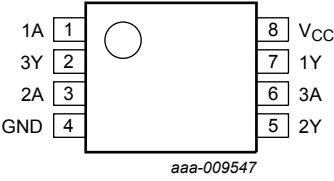


**Fig. 3. Logic diagram (one Schmitt trigger)**

## 7. Pinning information

### 7.1. Pinning

**74HC3G14-Q100**  
**74HCT3G14-Q100**



**Fig. 4. Pin configuration SOT505-2 (TSSOP8) and SOT765-1 (VSSOP8)**

### 7.2. Pin description

Table 3. Pin description

| Symbol          | Pin     | Description    |
|-----------------|---------|----------------|
| 1A, 2A, 3A      | 1, 3, 6 | data input     |
| GND             | 4       | ground (0 V)   |
| 1Y, 2Y, 3Y      | 7, 5, 2 | data output    |
| V <sub>CC</sub> | 8       | supply voltage |

## 8. Functional description

**Table 4. Function table**

*H = HIGH voltage level; L = LOW voltage level.*

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | H      |
| H     | L      |

## 9. Limiting values

**Table 5. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).*

| Symbol    | Parameter               | Conditions   | Min  | Max      | Unit |
|-----------|-------------------------|--|------|----------|------|
| $V_{CC}$  | supply voltage          |  | -0.5 | +7.0     | V    |
| $I_{IK}$  | input clamping current  | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ [1] | -    | $\pm 20$ | mA   |
| $I_{OK}$  | output clamping current | $V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$ [1] | -    | $\pm 20$ | mA   |
| $I_O$     | output current          | $V_O = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$ [1]       | -    | $\pm 25$ | mA   |
| $I_{CC}$  | supply current          | [1]  | -    | +50      | mA   |
| $I_{GND}$ | ground current          | [1]  | -50  | -        | mA   |
| $T_{stg}$ | storage temperature     |  | -65  | +150     | °C   |
| $P_{tot}$ | total power dissipation | [2]  | -    | 300      | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of  $P_{tot}$  derates linearly with 2.5 mW/K.  
For VSSOP8 package: above 110 °C the value of  $P_{tot}$  derates linearly with 8 mW/K.

## 10. Recommended operating conditions

**Table 6. Recommended operating conditions**

*Voltages are referenced to GND (ground = 0 V).*

| Symbol    | Parameter           | Conditions | 74HC3G14-Q100 |     |          | 74HCT3G14-Q100 |     |          | Unit |
|-----------|---------------------|------------|---------------|-----|----------|----------------|-----|----------|------|
|           |                     |            | Min           | Typ | Max      | Min            | Typ | Max      |      |
| $V_{CC}$  | supply voltage      |            | 2.0           | 5.0 | 6.0      | 4.5            | 5.0 | 5.5      | V    |
| $V_I$     | input voltage       |            | 0             | -   | $V_{CC}$ | 0              | -   | $V_{CC}$ | V    |
| $V_O$     | output voltage      |            | 0             | -   | $V_{CC}$ | 0              | -   | $V_{CC}$ | V    |
| $T_{amb}$ | ambient temperature |            | -40           | +25 | +125     | -40            | +25 | +125     | °C   |

## 11. Static characteristics

**Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V). All typical values are measured at  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

| Symbol                | Parameter                 | Conditions   | 25 °C |      |           | -40 °C to +85 °C |           | -40 °C to +125 °C |           | Unit          |
|-----------------------|---------------------------|--|-------|------|-----------|------------------|-----------|-------------------|-----------|---------------|
|                       |                           |  | Min   | Typ  | Max       | Min              | Max       | Min               | Max       |               |
| <b>74HC3G14-Q100</b>  |                           |  |       |      |           |                  |           |                   |           |               |
| $V_{OH}$              | HIGH-level output voltage | $V_I = V_{T+}$ or $V_{T-}$   |       |      |           |                  |           |                   |           |               |
|                       |                           | $I_O = -20\text{ }\mu\text{A}$ ; $V_{CC} = 2.0\text{ V}$   | 1.9   | 2.0  | -         | 1.9              | -         | 1.9               | -         | V             |
|                       |                           | $I_O = -20\text{ }\mu\text{A}$ ; $V_{CC} = 4.5\text{ V}$   | 4.4   | 4.5  | -         | 4.4              | -         | 4.4               | -         | V             |
|                       |                           | $I_O = -20\text{ }\mu\text{A}$ ; $V_{CC} = 6.0\text{ V}$   | 5.9   | 6.0  | -         | 5.9              | -         | 5.9               | -         | V             |
|                       |                           | $I_O = -4.0\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$   | 4.18  | 4.32 | -         | 4.13             | -         | 3.7               | -         | V             |
|                       |                           | $I_O = -5.2\text{ mA}$ ; $V_{CC} = 6.0\text{ V}$   | 5.68  | 5.81 | -         | 5.63             | -         | 5.2               | -         | V             |
| $V_{OL}$              | LOW-level output voltage  | $V_I = V_{T+}$ or $V_{T-}$   |       |      |           |                  |           |                   |           |               |
|                       |                           | $I_O = 20\text{ }\mu\text{A}$ ; $V_{CC} = 2.0\text{ V}$  | -     | 0    | 0.1       | -                | 0.1       | -                 | 0.1       | V             |
|                       |                           | $I_O = 20\text{ }\mu\text{A}$ ; $V_{CC} = 4.5\text{ V}$  | -     | 0    | 0.1       | -                | 0.1       | -                 | 0.1       | V             |
|                       |                           | $I_O = 20\text{ }\mu\text{A}$ ; $V_{CC} = 6.0\text{ V}$  | -     | 0    | 0.1       | -                | 0.1       | -                 | 0.1       | V             |
|                       |                           | $I_O = 4.0\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$  | -     | 0.15 | 0.26      | -                | 0.33      | -                 | 0.4       | V             |
|                       |                           | $I_O = 5.2\text{ mA}$ ; $V_{CC} = 6.0\text{ V}$  | -     | 0.16 | 0.26      | -                | 0.33      | -                 | 0.4       | V             |
| $I_I$                 | input leakage current     | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0\text{ V}$   | -     | -    | $\pm 0.1$ | -                | $\pm 1.0$ | -                 | $\pm 1.0$ | $\mu\text{A}$ |
| $I_{CC}$              | supply current            | per input pin; $V_{CC} = 6.0\text{ V}$ ;<br>$V_I = V_{CC}$ or GND; $I_O = 0\text{ A}$                        | -     | -    | 1.0       | -                | 10        | -                 | 20        | $\mu\text{A}$ |
| $C_I$                 | input capacitance         |  | -     | 2.0  | -         | -                | -         | -                 | -         | pF            |
| <b>74HCT3G14-Q100</b> |                           |  |       |      |           |                  |           |                   |           |               |
| $V_{OH}$              | HIGH-level output voltage | $V_I = V_{T+}$ or $V_{T-}$   |       |      |           |                  |           |                   |           |               |
|                       |                           | $I_O = -20\text{ }\mu\text{A}$ ; $V_{CC} = 4.5\text{ V}$   | 4.4   | 4.5  | -         | 4.4              | -         | 4.4               | -         | V             |
|                       |                           | $I_O = -4.0\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$   | 4.18  | 4.32 | -         | 4.13             | -         | 3.7               | -         | V             |
| $V_{OL}$              | LOW-level output voltage  | $V_I = V_{IH}$ or $V_{IL}$   |       |      |           |                  |           |                   |           |               |
|                       |                           | $I_O = 20\text{ }\mu\text{A}$ ; $V_{CC} = 4.5\text{ V}$  | -     | 0    | 0.1       | -                | 0.1       | -                 | 0.1       | V             |
|                       |                           | $I_O = 4.0\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$  | -     | 0.15 | 0.26      | -                | 0.33      | -                 | 0.4       | V             |
| $I_I$                 | input leakage current     | $V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$   | -     | -    | $\pm 0.1$ | -                | $\pm 1.0$ | -                 | $\pm 1.0$ | $\mu\text{A}$ |
| $I_{CC}$              | supply current            | per input pin; $V_{CC} = 5.5\text{ V}$ ;<br>$V_I = V_{CC}$ or GND; $I_O = 0\text{ A}$                        | -     | -    | 1.0       | -                | 10        | -                 | 20        | $\mu\text{A}$ |
| $\Delta I_{CC}$       | additional supply current | per input; $V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$ ;<br>$V_I = V_{CC} - 2.1\text{ V}$ ; $I_O = 0\text{ A}$ | -     | -    | 300       | -                | 375       | -                 | 410       | $\mu\text{A}$ |
| $C_I$                 | input capacitance         |  | -     | 2.0  | -         | -                | -         | -                 | -         | pF            |

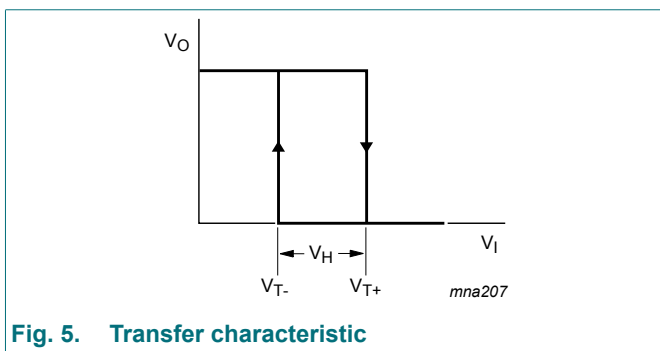
### 11.1. Transfer characteristics

**Table 8. Transfer characteristics**

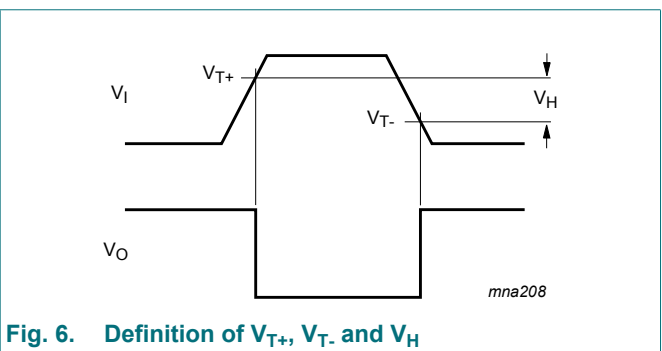
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10.

| Symbol                | Parameter  | Conditions              | 25 °C |      |      | -40 °C to +125 °C |             |              | Unit |
|-----------------------|--|-------------------------|-------|------|------|-------------------|-------------|--------------|------|
|                       |  |                         | Min   | Typ  | Max  | Min               | Max (85 °C) | Max (125 °C) |      |
| <b>74HC3G14-Q100</b>  |  |                         |       |      |      |                   |             |              |      |
| V <sub>T+</sub>       | positive-going threshold voltage   | see Fig. 5, Fig. 6      |       |      |      |                   |             |              |      |
|                       |  | V <sub>CC</sub> = 2.0 V | 1.00  | 1.18 | 1.50 | 1.00              | 1.50        | 1.50         | V    |
|                       |  | V <sub>CC</sub> = 4.5 V | 2.30  | 2.60 | 3.15 | 2.30              | 3.15        | 3.15         | V    |
|                       |  | V <sub>CC</sub> = 6.0 V | 3.00  | 3.46 | 4.20 | 3.00              | 4.20        | 4.20         | V    |
| V <sub>T-</sub>       | negative-going threshold voltage   | see Fig. 5, Fig. 6      |       |      |      |                   |             |              |      |
|                       |  | V <sub>CC</sub> = 2.0 V | 0.30  | 0.60 | 0.90 | 0.30              | 0.90        | 0.90         | V    |
|                       |  | V <sub>CC</sub> = 4.5 V | 1.13  | 1.47 | 2.00 | 1.13              | 2.00        | 2.00         | V    |
|                       |  | V <sub>CC</sub> = 6.0 V | 1.50  | 2.06 | 2.60 | 1.50              | 2.60        | 2.60         | V    |
| V <sub>H</sub>        | hysteresis voltage (V <sub>T+</sub> - V <sub>T-</sub> ); see Fig. 5, Fig. 6 and Fig. 7 |                         |       |      |      |                   |             |              |      |
|                       |  | V <sub>CC</sub> = 2.0 V | 0.30  | 0.60 | 1.00 | 0.30              | 1.00        | 1.00         | V    |
|                       |  | V <sub>CC</sub> = 4.5 V | 0.60  | 1.13 | 1.40 | 0.60              | 1.40        | 1.40         | V    |
|                       |  | V <sub>CC</sub> = 6.0 V | 0.80  | 1.40 | 1.70 | 0.80              | 1.70        | 1.70         | V    |
| <b>74HCT3G14-Q100</b> |  |                         |       |      |      |                   |             |              |      |
| V <sub>T+</sub>       | positive-going threshold voltage   | see Fig. 5, Fig. 6      |       |      |      |                   |             |              |      |
|                       |  | V <sub>CC</sub> = 4.5 V | 1.20  | 1.58 | 1.90 | 1.20              | 1.90        | 1.90         | V    |
|                       |  | V <sub>CC</sub> = 5.5 V | 1.40  | 1.78 | 2.10 | 1.40              | 2.10        | 2.10         | V    |
| V <sub>T-</sub>       | negative-going threshold voltage   | see Fig. 5, Fig. 6      |       |      |      |                   |             |              |      |
|                       |  | V <sub>CC</sub> = 4.5 V | 0.50  | 0.87 | 1.20 | 0.50              | 1.20        | 1.20         | V    |
|                       |  | V <sub>CC</sub> = 5.5 V | 0.60  | 1.11 | 1.40 | 0.60              | 1.40        | 1.40         | V    |
| V <sub>H</sub>        | hysteresis voltage (V <sub>T+</sub> - V <sub>T-</sub> ); see Fig. 5, Fig. 6 and Fig. 8 |                         |       |      |      |                   |             |              |      |
|                       |  | V <sub>CC</sub> = 4.5 V | 0.40  | 0.71 | -    | 0.40              | -           | -            | V    |
|                       |  | V <sub>CC</sub> = 5.5 V | 0.40  | 0.67 | -    | 0.40              | -           | -            | V    |

### 11.2. Transfer characteristics waveforms



**Fig. 5. Transfer characteristic**



**Fig. 6. Definition of V<sub>T+</sub>, V<sub>T-</sub> and V<sub>H</sub>**

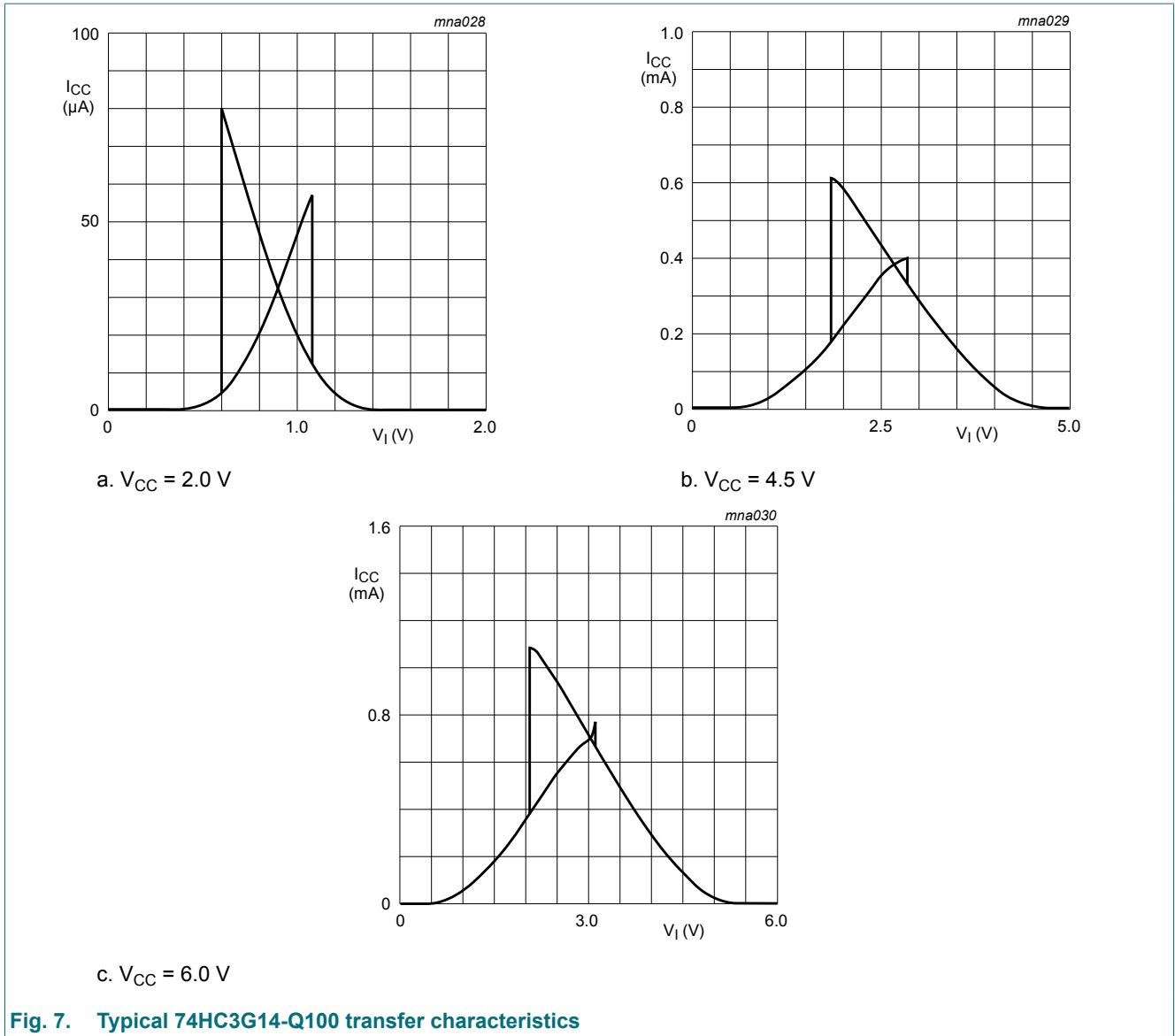


Fig. 7. Typical 74HC3G14-Q100 transfer characteristics

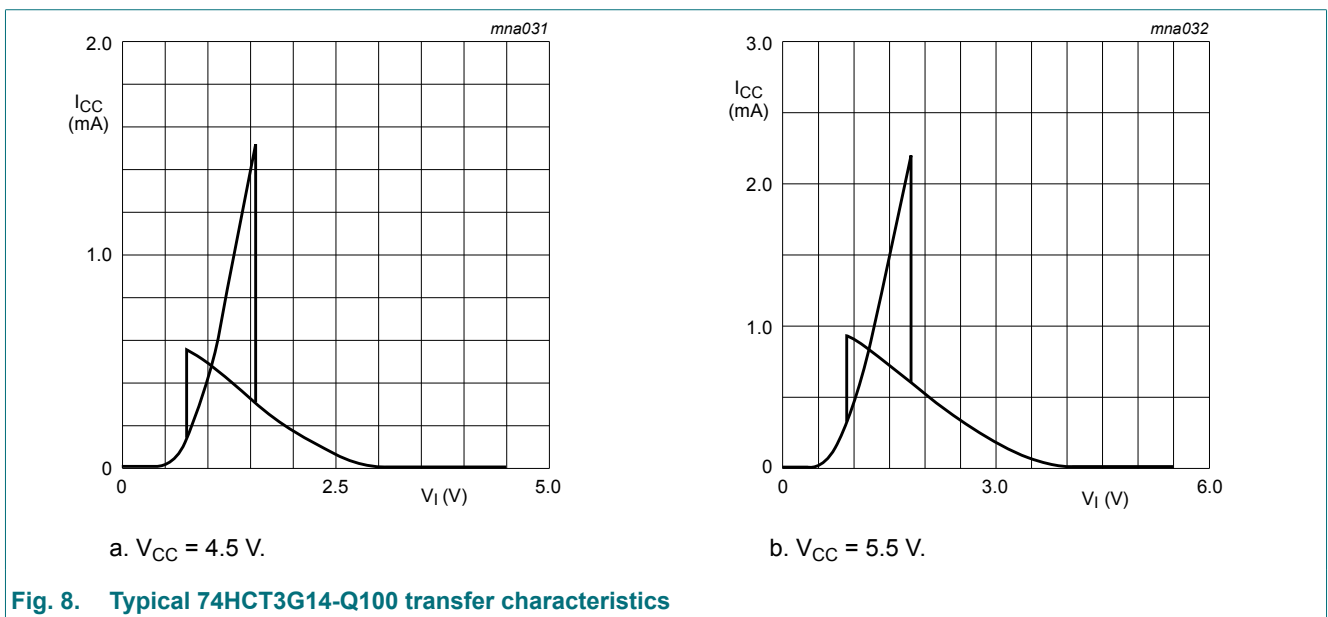


Fig. 8. Typical 74HCT3G14-Q100 transfer characteristics

## 12. Dynamic characteristics

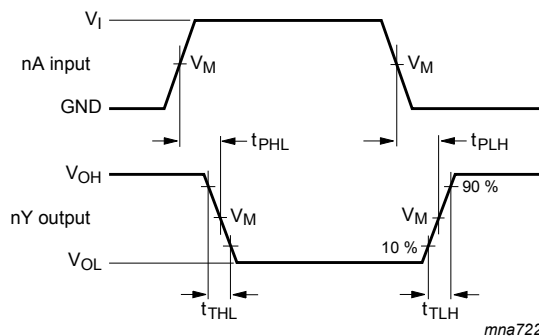
**Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10.

| Symbol                | Parameter                     | Conditions  | 25 °C |     |     | -40 °C to +125 °C |             |              | Unit |
|-----------------------|-------------------------------|---|-------|-----|-----|-------------------|-------------|--------------|------|
|                       |                               |   | Min   | Typ | Max | Min               | Max (85 °C) | Max (125 °C) |      |
| <b>74HC3G14-Q100</b>  |                               |   |       |     |     |                   |             |              |      |
| t <sub>pd</sub>       | propagation delay             | nA to nY; see Fig. 9 [1]                            |       |     |     |                   |             |              |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                             | -     | 53  | 125 | -                 | 155         | 190          | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                             | -     | 16  | 25  | -                 | 31          | 38           | ns   |
|                       |                               | V <sub>CC</sub> = 6.0 V                             | -     | 13  | 21  | -                 | 26          | 32           | ns   |
| t <sub>t</sub>        | transition time               | nY; see Fig. 9 [2]                                  |       |     |     |                   |             |              |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                             | -     | 20  | 75  | -                 | 95          | 110          | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                             | -     | 7   | 15  | -                 | 19          | 22           | ns   |
|                       |                               | V <sub>CC</sub> = 6.0 V                             | -     | 5   | 13  | -                 | 16          | 19           | ns   |
| C <sub>PD</sub>       | power dissipation capacitance | V <sub>I</sub> = GND to V <sub>CC</sub> [3]         | -     | 10  | -   | -                 | -           | -            | pF   |
| <b>74HCT3G14-Q100</b> |                               |   |       |     |     |                   |             |              |      |
| t <sub>pd</sub>       | propagation delay             | nA to nY; V <sub>CC</sub> = 4.5 V; see Fig. 9 [1]   | -     | 21  | 32  | -                 | 40          | 48           | ns   |
| t <sub>t</sub>        | transition time               | nY; V <sub>CC</sub> = 4.5 V; see Fig. 9 [2]         | -     | 6   | 15  | -                 | 19          | 22           | ns   |
| C <sub>PD</sub>       | power dissipation capacitance | V <sub>I</sub> = GND to V <sub>CC</sub> - 1.5 V [3] | -     | 10  | -   | -                 | -           | -            | pF   |

- [1] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>
- [2] t<sub>t</sub> is the same as t<sub>TLH</sub> and t<sub>THL</sub>
- [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = output load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

### 12.1. Waveforms and test circuit



Measurement points are given in Table 10.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

**Fig. 9. The data input (nA) to output (nY) propagation delays and output transition times**

Table 10. Measurement points

| Type           | Input       | Output      |
|----------------|-------------|-------------|
|                | $V_M$       | $V_M$       |
| 74HC3G14-Q100  | $0.5V_{CC}$ | $0.5V_{CC}$ |
| 74HCT3G14-Q100 | 1.3 V       | 1.3 V       |



Fig. 10. Test circuit for measuring switching times

Table 11. Test data

| Type           | Input           |             | Load  |              | S1 position        |
|----------------|-----------------|-------------|-------|--------------|--------------------|
|                | $V_I$           | $t_r, t_f$  | $C_L$ | $R_L$        | $t_{PHL}, t_{PLH}$ |
| 74HC3G14-Q100  | GND to $V_{CC}$ | $\leq 6$ ns | 50 pF | 1 k $\Omega$ | open               |
| 74HCT3G14-Q100 | GND to 3.0 V    | $\leq 6$ ns | 50 pF | 1 k $\Omega$ | open               |



### 13. Application information

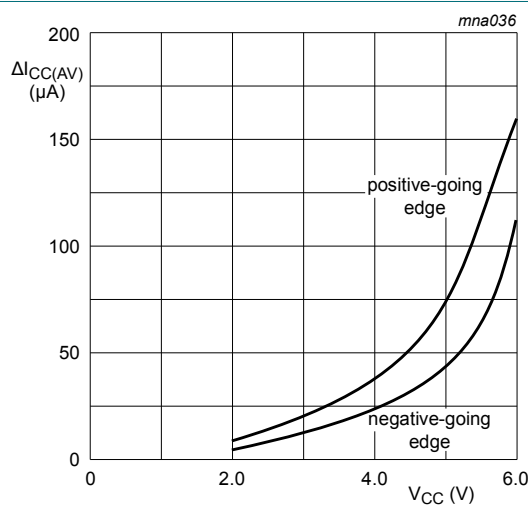
The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

$$P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC} \text{ where:}$$

- $P_{add}$  = additional power dissipation ( $\mu W$ );
- $f_i$  = input frequency (MHz);
- $t_r$  = input rise time (ns); 10 % to 90 %;
- $t_f$  = input fall time (ns); 90 % to 10 %;
- $\Delta I_{CC(AV)}$  = average additional supply current ( $\mu A$ ).

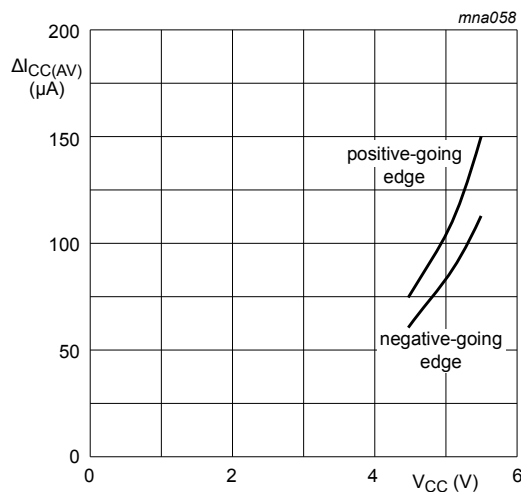
$\Delta I_{CC(AV)}$  differs with positive or negative input transitions, as shown in [Fig. 11](#) and [Fig. 12](#).

An example of a relaxation circuit using the 74HC3G14-Q100/74HCT3G14-Q100 is shown in [Fig. 13](#).



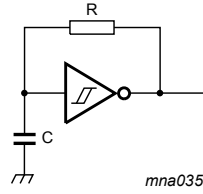
Linear change of  $V_I$  between  $0.1V_{CC}$  to  $0.9V_{CC}$ .

**Fig. 11.  $\Delta I_{CC(AV)}$  as a function of  $V_{CC}$  for 74HC3G14-Q100**



Linear change of  $V_I$  between  $0.1V_{CC}$  to  $0.9V_{CC}$ .

**Fig. 12.  $\Delta I_{CC(AV)}$  as a function of  $V_{CC}$  for 74HCT3G14-Q100**

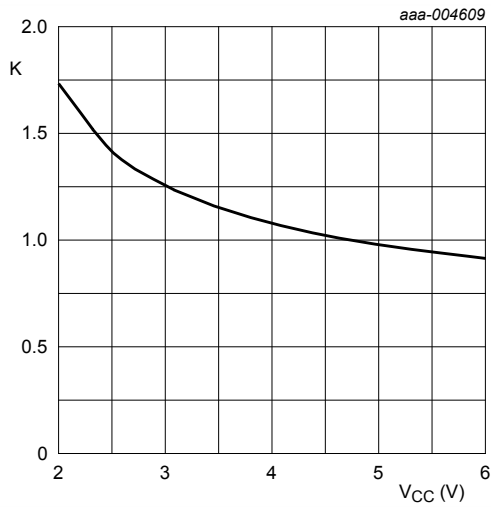


For 74HC3G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.8 \times RC}$

For 74HCT3G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.67 \times RC}$

For K-factor, see [Fig. 14](#)

**Fig. 13. Relaxation oscillator**



a. K-factor for 74HC3G14-Q100



b. K-factor for 74HCT3G14-Q100

**Fig. 14. Typical K-factor for relaxation oscillator**

### 14. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2



Fig. 15. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



Fig. 16. Package outline SOT765-1 (VSSOP8)

## 15. Abbreviations

Table 12. Abbreviations

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MIL     | Military                                |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 16. Revision history

Table 13. Revision history

| Document ID           | Release date  | Data sheet status  | Change notice | Supersedes            |
|-----------------------|---|--------------------|---------------|-----------------------|
| 74HC_HCT3G14_Q100 v.3 | 20190201  | Product data sheet | -             | 74HC_HCT3G14_Q100 v.2 |
| Modifications:        | <ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Package outline drawing <a href="#">SOT765-1</a> (VSSOP8) updated.</li> </ul> |                    |               |                       |
| 74HC_HCT3G14_Q100 v.2 | 20131209  | Product data sheet | -             | 74HC_HCT3G14_Q100 v.1 |
| Modifications:        | <ul style="list-style-type: none"> <li><a href="#">Fig. 14</a> added (typical K-factor for relaxation oscillator).</li> </ul>   |                    |               |                       |
| 74HC_HCT3G14_Q100 v.1 | 20131115  | Product data sheet | -             | -                     |

## 17. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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